



DGD2108

HALF-BRIDGE GATE DRIVER IN SO-8

Description

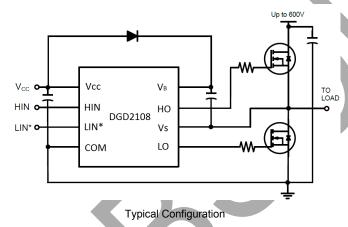
The DGD2108 is a high-voltage / high-speed gate driver capable of driving N-Channel MOSFETs and IGBTs in a half bridge configuration. High-voltage processing techniques enable the DGD2108's high-side to switch to 600V in a bootstrap operation.

The DGD2108 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) for easy interfacing with controlling devices. The driver outputs feature high-pulse current buffers designed for minimum driver cross conduction. Internal deadtime protects high-voltage MOSFETs.

The DGD2108 is offered in SO-8 package, the operating temperature extends from -40°C to +125°C.

Applications

- DC-DC Converters
- DC-AC Inverters
- AC-DC Power Supplies
- Motor Controls
- Class D Power Amplifiers



Features

- Floating High-Side Driver in Bootstrap Operation to 600V
- Drives Two N-Channel MOSFETs or IGBTs in a Half Bridge Configuation
- Outputs Tolerant to Negative Transients
- Internal Logic and Dead Time of 540ns to Protect MOSFETs
- Wide Logic and Low-Side Gate Driver Supply Voltage: 10V to 20V
- Logic Inputs (HIN and LIN*) 3.3V Capability
- Schmitt Triggered Logic Inputs with Internal Pull Down
- Undervoltage Lockout for High and Low Side Drivers
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony free. "Green" Device (Note 3)

Mechanical Data

- Case: SO-8 (Type TH)
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.075 grams (Approximate)



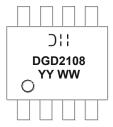
Ordering Information (Note 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DGD2108S8-13	DGD2108	13	12	2,500

Notes

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

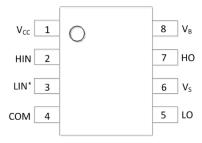
Marking Information



DGD2108 Document number: DS38287 Rev. 6 - 4 1 of 12 www.diodes.com



Pin Diagrams

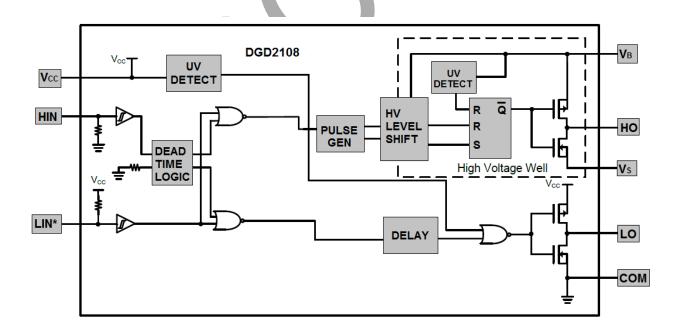


Top view SO-8

Pin Descriptions

Pin Number	Pin Name	Function
1	V _{CC}	Low-side and logic fixed supply
2	HIN	Logic input for high-side gate driver output, in phase with HO
3	LIN*	Logic input for low-side gate driver output, out of phase with LO
4	COM	Low-side return
5	LO	Low-side gate drive output
6	Vs	High-side floating supply return
7	НО	High-side gate drive output
8	V_{B}	High-side floating supply

Functional Block Diagram





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-Side Floating Supply Voltage	V _B	-0.3 to +624	V
High-Side Floating Supply Offset Voltage	Vs	V _B -24 to V _B +0.3	V
High-Side Floating Output Voltage	V _{HO}	V _S -0.3 to V _B +0.3	V
Offset Supply Voltage Transient	dV _S / dt	50	V/ns
Low-Side and Logic Fixed Supply Voltage	V _{CC}	-0.3 to +24	V
Low-Side Output Voltage	V_{LO}	-0.3 to V _{CC} +0.3	V
Logic Input Voltage (HIN and LIN*)	V _{IN}	-0.3 to V _{CC} +0.3	V

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	P_{D}	0.625	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	200	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	T _{STG}	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply Absolute Voltage	V_{B}	V _S + 10	V _S + 20	V
High-Side Floating Supply Offset Voltage	V _S	(Note 6)	600	V
High-Side Floating Output Voltage	V _{HO}	Vs	V_{B}	V
Low-Side and Logic Fixed Supply Voltage	Vcc	10	20	V
Low-Side Output Voltage	V_{LO}	0	V _{CC}	V
Logic Input Voltage	V _{IN}	0	5	V
Ambient Temperature	T _A	-40	+125	°C

Note: 6. Logic operation for V_S of -5V to +600V.





DC Electrical Characteristics (V_{BIAS} (V_{CC}, V_{BS}) = 15V, @T_A = +25°C, unless otherwise specified.) (Note 7)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Logic "1" Input Voltage (Note 8)	V_{IH}	2.5	_	I	>	V _{CC} = 10V to 20V
Logic "0" Input Voltage (Note 8)	V_{IL}	_	_	0.6	V	V _{CC} = 10V to 20V
High Level Output Voltage, V _{BIAS} - V _O	V_{OH}	_	0.05	0.2	V	I _O = 2mA
Low Level Output Voltage, Vo	V_{OL}	_	0.2	0.1	>	I _O = 2mA
Offset Supply Leakage Current	I_{LK}	_	_	50	μΑ	$V_B = V_S = 600V$
Quiescent V _{BS} Supply Current	I _{BSQ}	20	75	130	μΑ	V _{IN} = 0V or 5V
Quiescent V _{CC} Supply Current	Iccq	0.4	1.0	1.6	mA	V _{IN} = 0V or 5V
Logic "1" Input Bias Current	I _{IN+}	_	5	20	μA	HIN = 5V, LIN* = 0V
Logic "0" Input Bias Current	I _{IN-}	_	_	5	μA	HIN = 0V, LIN* = 5V
V _{BS} Supply Undervoltage Positive Going Threshold	V_{BSUV+}	8.0	8.9	9.8	>	
V _{BS} Supply Undervoltage Negative Going Threshold	V_{BSUV-}	7.4	8.2	9.0	V	
V _{CC} Supply Undervoltage Positive Going Threshold	$V_{\text{CCUV+}}$	8.0	8.9	9.8	>	_
V _{CC} Supply Undervoltage Negative Going Threshold	V _{CCUV} -	7.4	8.2	9.0	>	_
Hysteresis	V _{CCUVH} V _{BSUVH}	0.3	0.7		V	
Tysteresis					V	_
Output High Short Circuit Pulsed Current	I _{O+}	120	290	-	mA	V _O = 0V, PW ≤ 10μs
Output Low Short Circuit Pulsed Current	l ₀₋	250	600	_	mA	V _O = 15V, PW ≤ 10μs

Notes:

AC Electrical Characteristics (V_{BIAS} (V_{CC}, V_{BS}) = 15V, C_L = 1000pF, @T_A = +25°C, unless otherwise specified.)

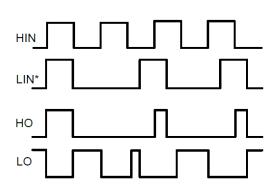
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-On Propagation Delay	ton	7	220	300	ns	$V_S = 0V$
Turn-Off Propagation Delay	toff	-	200	280	ns	V _S = 0V or 600V
Delay Matching, ton - toff	t _{DMON}	-	_	30	ns	_
Turn-On Rise Time	t _r	_	100	220	ns	$V_S = 0V$
Turn-Off Fall Time	t _f	_	35	80	ns	$V_S = 0V$
Deadtime: t _{DT LO-HO} & t _{DT HO-LO}	tor	400	540	680	ns	_
Deadtime Matching: t _{DT LO-HO} - t _{DT HO-LO}	t _{MDT}	_	0	60	ns	_

^{7.} The V_{IN} and I_{IN} parameters are referenced to V_{SS} and are applicable to the two logic input pins: HIN and LIN*. The V_O and I_O parameters are referenced to COM and are applicable to the respective output pins: HO and LO.

^{8.} For optimal operation, it is recommended that the input pulses (HIN and LIN*) should have a minimum amplitude of 2.5V wiith a minimum pulse width of 1µs.



Timing Waveforms



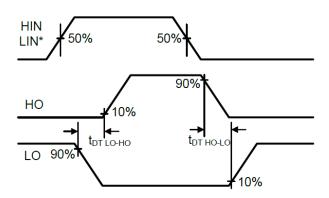
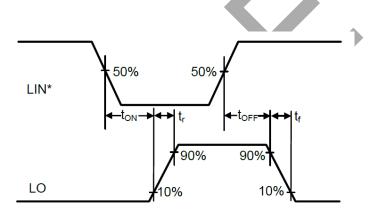


Figure 1. Input / Output Timing Diagram

Figure 2. Deadtime Waveform Definitions



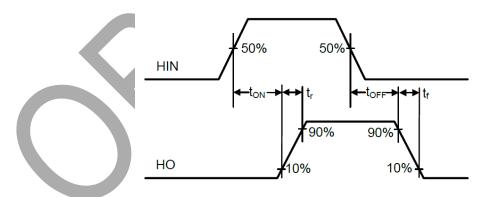


Figure 3. Switching Time Waveform Definitions



Typical Performance Characteristics (V_{CC} = 15V, @T_A = +25°C, unless otherwise specified.)

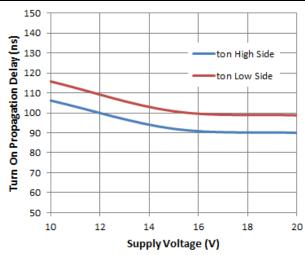


Figure 4. Turn-on Propagation Delay vs. Supply Voltage

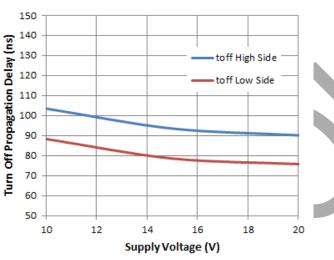


Figure 6. Turn-off Propagation Delay vs. Supply Voltage

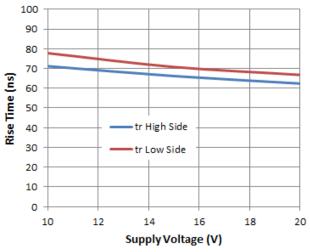


Figure 8. Rise Time vs. Supply Voltage

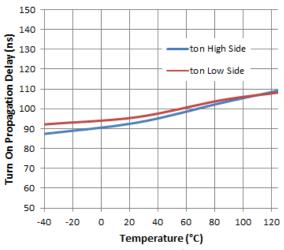


Figure 5. Turn-on Propagation Delay vs. Temperature

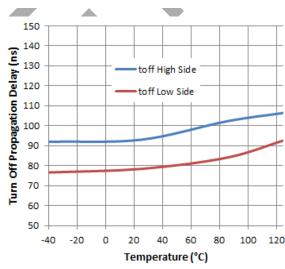


Figure 7. Turn-off Propagation Delay vs. Temperature

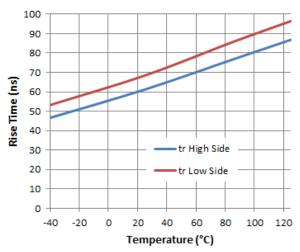


Figure 9. Rise Time vs. Temperature



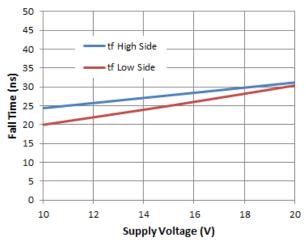


Figure 10. Fall Time vs. Supply Voltage

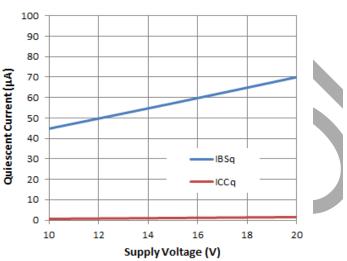


Figure 12. Quiescent Current vs. Supply Voltage

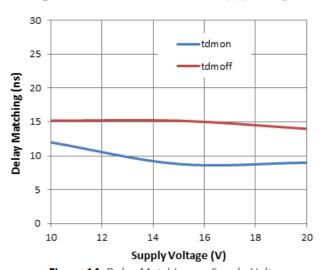


Figure 14. Delay Matching vs. Supply Voltage

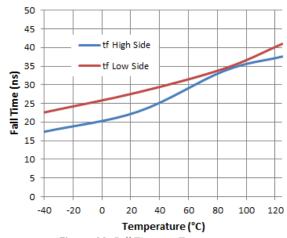


Figure 11. Fall Time vs. Temperature

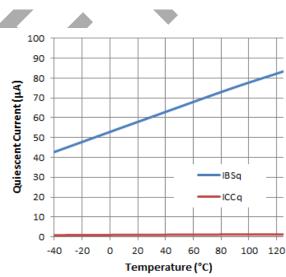


Figure 13. Quiescent Current vs. Temperature

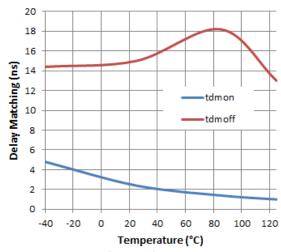


Figure 15. Delay Matching vs. Temperature



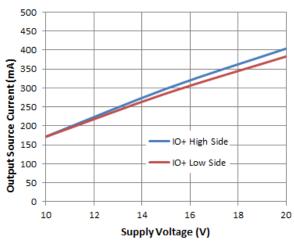


Figure 16. Output Source Current vs. Supply Voltage

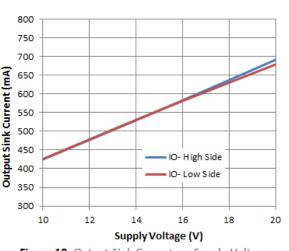


Figure 18. Output Sink Current vs. Supply Voltage

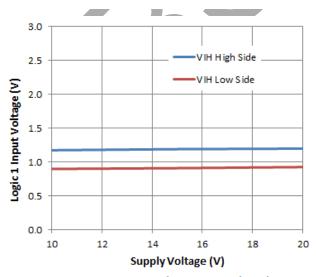


Figure 20. Logic 1 Input Voltage vs. Supply Voltage

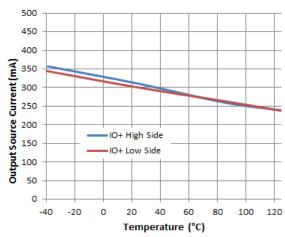


Figure 17. Output Source Current vs. Temperature

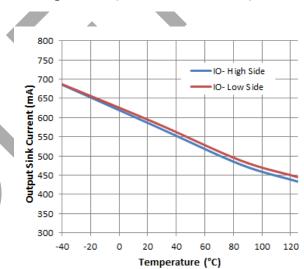


Figure 19. Output Sink Current vs. Temperature

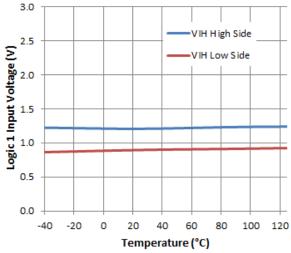


Figure 21. Logic 1 Input Voltage vs. Temperature



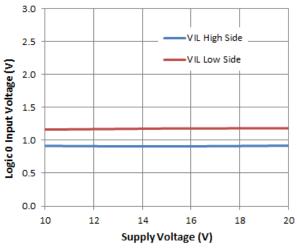


Figure 22. Logic O Input Voltage vs. Supply Voltage

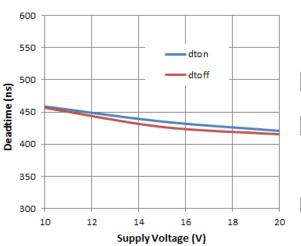


Figure 24. Deadtime vs. Supply Voltage

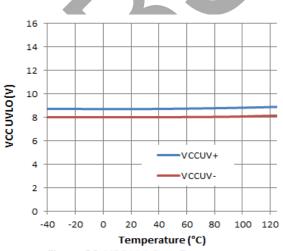


Figure 26. VCC UVLO vs. Temperature

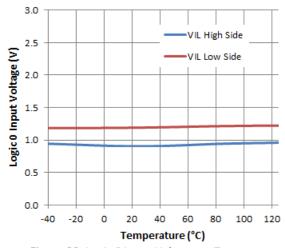


Figure 23. Logic 0 Input Voltage vs. Temperature

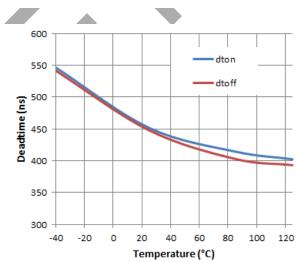


Figure 25. Deadtime vs. Temperature

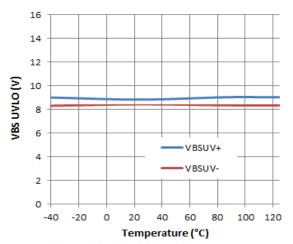


Figure 27. VBS UVLO vs. Temperature



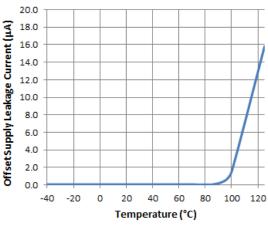


Figure 28. Offset Supply Leakage Current vs. Temperature

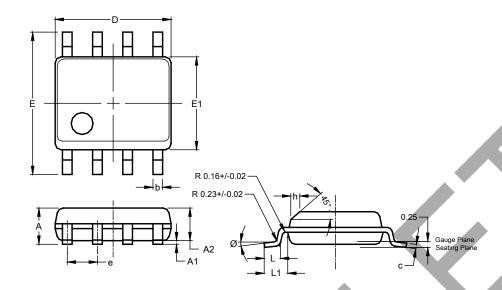




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8 (Type TH)

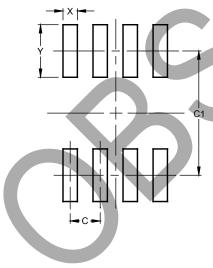


SO-8 (Type TH)						
Dim	Min	Max	Тур			
Α	1.35	1.75	-			
A1	0.10	0.25	-			
A2			1.45			
b	0.35	0.51				
C	0.190	0.248	-			
D	4.80	5.00	4.90			
Е	5.80	6.20	6.00			
E1	3.80	4.00	3.90			
е			1.27			
h	0.25	0.50				
Г	0.41	1.27				
Ţ			1.04			
Ø	0°	8°	1			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8 (Type TH)



Dimensions	Value (in mm)
С	1.27
C1	5.20
Х	0.60
Y	2.20

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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